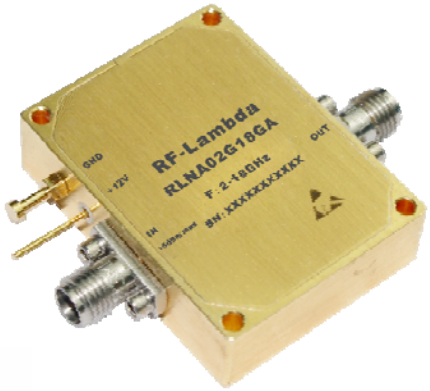
Ultra Wide Band Low Noise Amplifier 2GHz~18GHz



RoHS Compliant

Feature

- Gain: **29** dB Typical
- Noise Figure: 3.0dB Typical
- P1dB Output Power: +22dB m full band
- Supply Voltage: +12V @ 350mA
- 50 Ohm Matched Input / Output
- Size: 1.18" x 1.574" x 0.39"

Typical Applications

- Wireless Infrastructure
- RF Microwave & VSAT
- Military & Aerospace
- Test Instrument
- Fiber Optics

Electrical Specifications, TA = +25 ° C, With Vcc = +12V, 50 Ohm System

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range	2		8	8		18	GHz
Gain	29	30		27	28		dB
Gain Flatness		±0.8			±0.8		dB
Gain Variation Over Temperature(-45 ~ +85)		±1.0			±1.0		dB
Noise Figure		3.0	4.0		3.0	4.0	dB
Input Return Loss		14			16		dB
Output Return Loss		15			14		dB
Output Power for 1 dB Compression (P1dB)	24	25		22	23		dBm
Saturated Output Power (Psat)		26			24		dBm
Output Third Order Intercept (IP3)		30			25		dBm
Supply Current (Idd) (Vcc=+12V)		330	350		330	350	mA
Isolation S12	60	65		55	60		dB
Input Max Power(no damage)			+5			+5	dBm
Weight	85						g
Impedance	50						Ohms
Input /Output Connector	SMA-Female						
Finishing	Standard: Gold 40 micron; Nickel 220 micron thickness						
	Option: Gold 80 micron; Nickel 180 micron thickness						
Material	Aluminum/copper						
Package Sealing	Epoxy Sealing (Standard)						
	Hermetically Seal (Option with extra charge)						

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Absolute Maximum Ratings

Operating Voltage	+12V
RF Input Power	+5dB m
Operating Temperature(C°)	-45 to +85
Storage Temperature(C°)	-50 to +125

Biasing Up Procedure

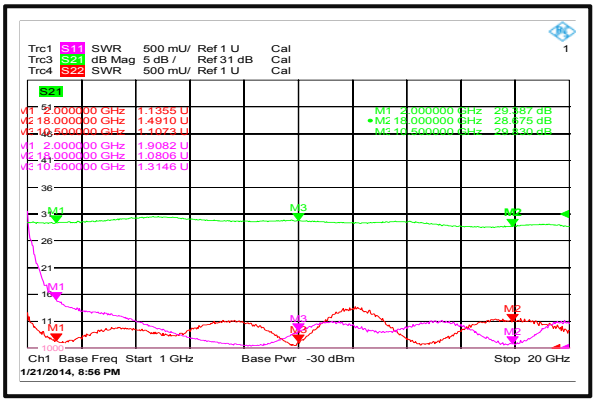
Step 1	Connect Ground Pin
Step 2	Connect input and output
Step 3	Connect +12V biasing
Power OFF Procedure	
Step 1	Turn off +12V biasing
Step 2	Remove RF connection
Step 3	Remove Ground.

Environment specifications

Operational Temperature (C°)	-45 to+85
Storage Temperature (C°)	-50 to +125
Altitude	30,000 ft. (Epoxy Seal Controlled environment) 60,000 ft 1.0psi min (Hermetically Seal Un-controlled environment) (Optional)
Vibration	25g rms (15 degree 2KHz) endurance, 1 hour per axis
Humidity	100% RH at 35c, 95%RH at 40°c
Shock	20G for 11msc half sin wave,3 axis both directions

Typical performance plots

Gain



Input Return Loss

Output Return Loss

Isolation

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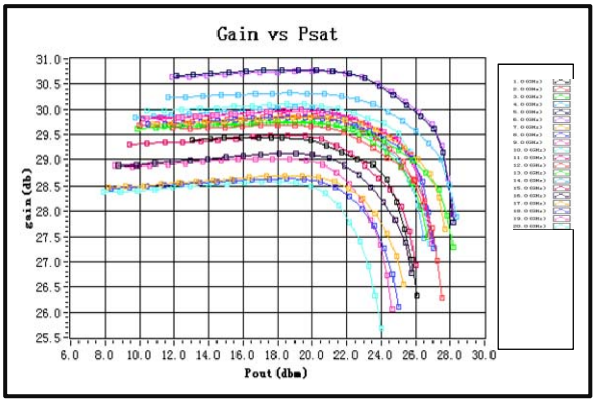
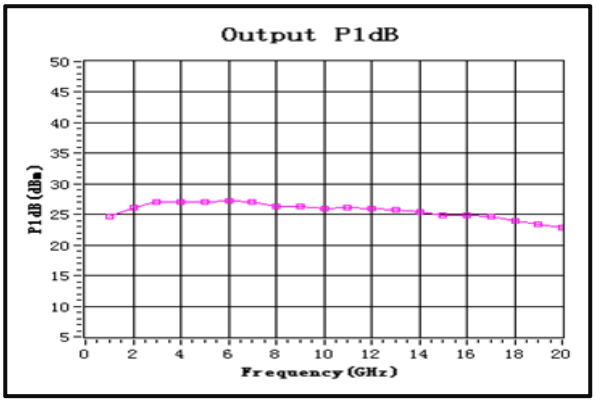
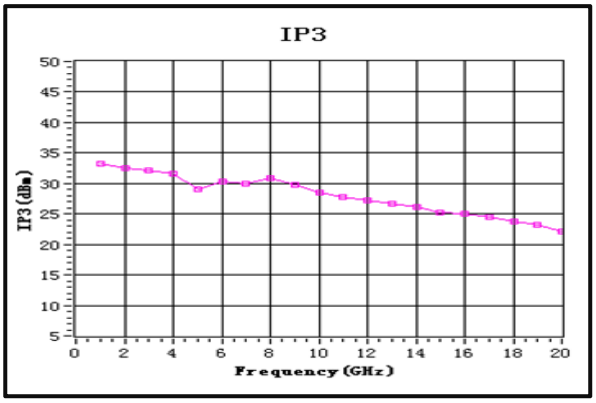
Cain vs. output power



P1dB vs. Frequency



Output Third Order Intercept (IP3)



Noise Figure

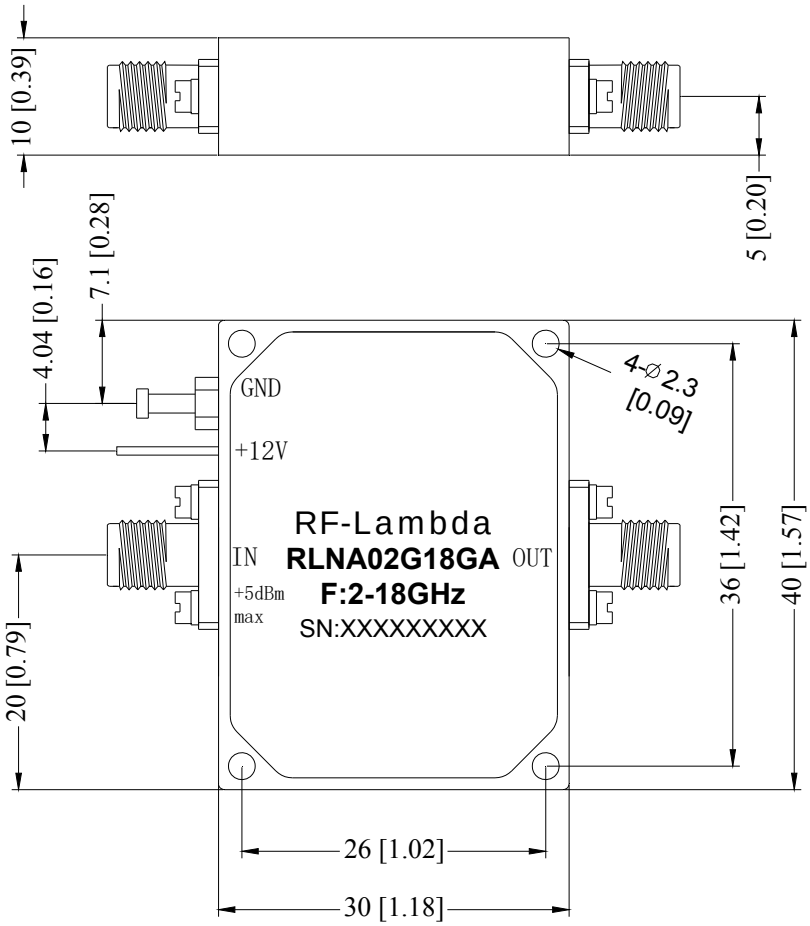
2nd Harmonic Wave output Power

3th Harmonic Wave output Power

4nd Harmonic Wave output Power

Outline Drawing:

All Dimensions in mm（inches）
Heat Sink required during operation



Ordering Information

Part No	ECCN	Description
RLNA02G18GA	EAR99	2-18GHz LNA Amplifier

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